

# New stable beam developments

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CAEN

GANIL COMMUNITY MEETING

2022

# Summary:

***I- Facility and equipments for the tests***

***II- Silicon beam production***

***III -Tungsten beam production***

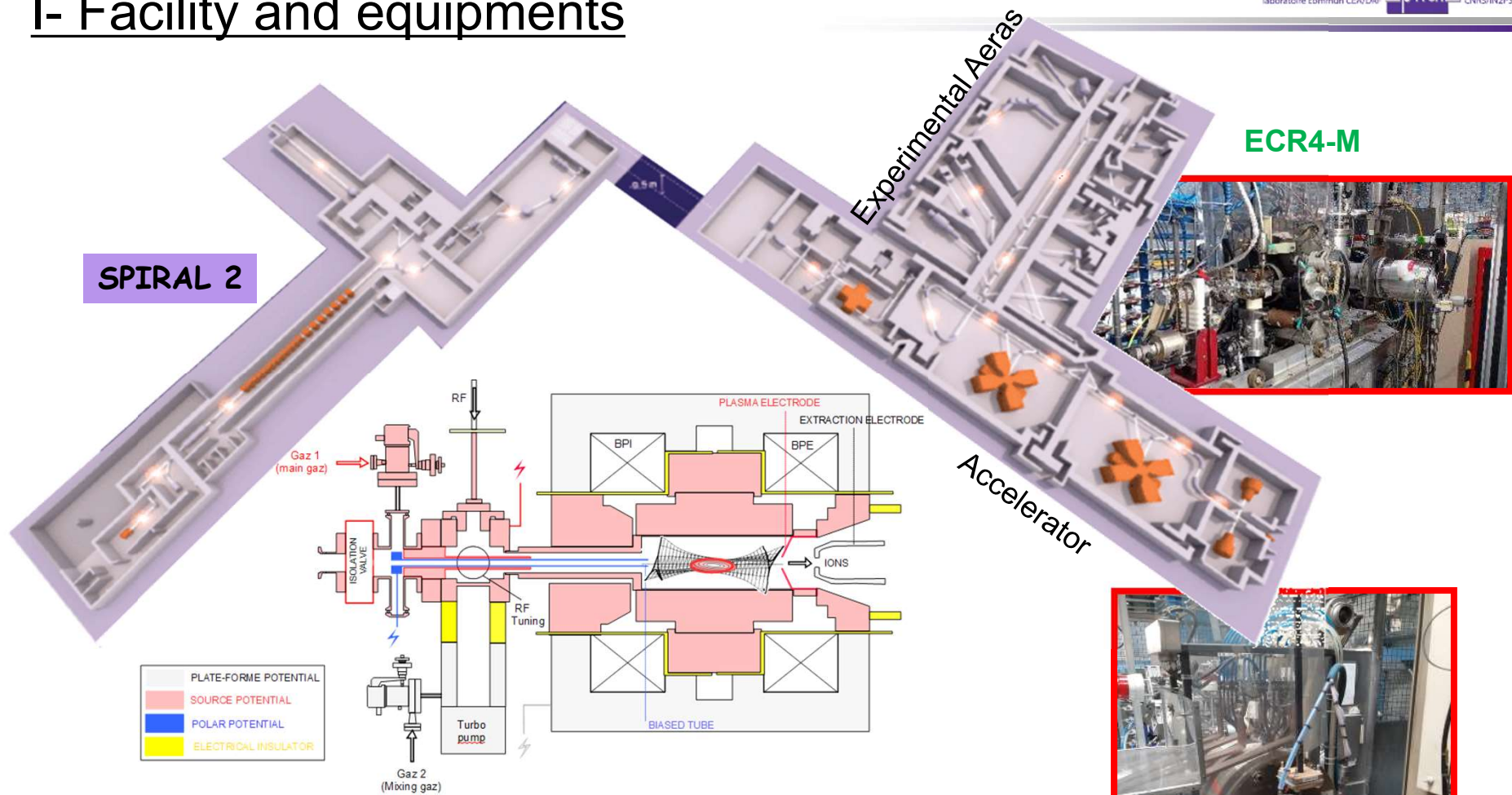
***IV: Tellurium beam production***

***V: Thorium beam production***

***VI: The First beams tests with HT oven***

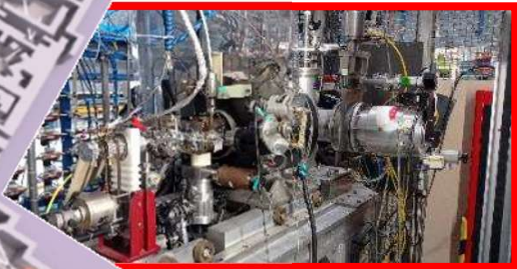
***VII: Conclusion***

# I- Facility and equipments



**ECR4 ion source : platform 100kV**  
**ECR4-M ion source : 25KV**

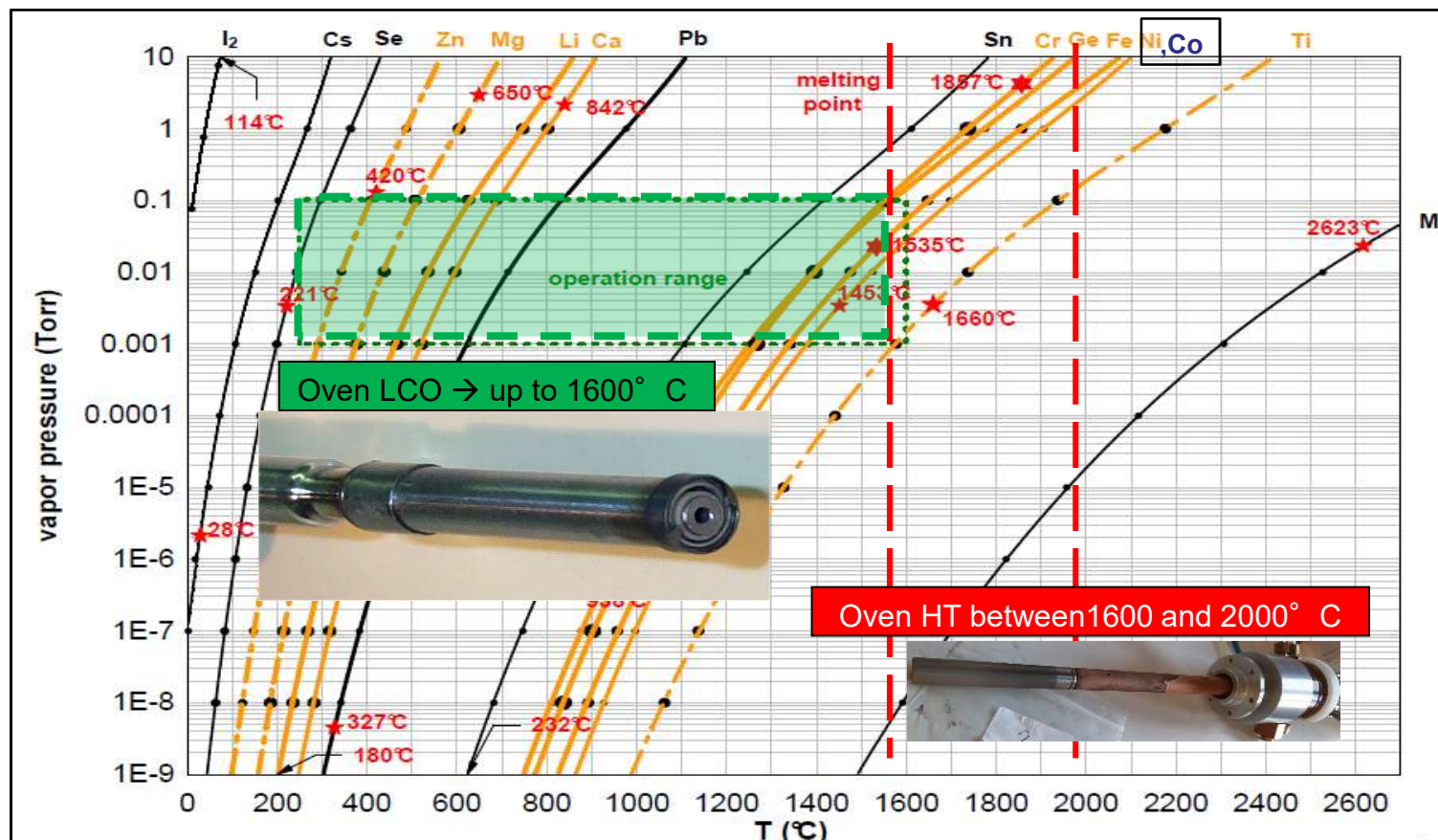
**Tests beams production in parallele of experiments**  
**→ tests 24/24H**



**ECR4**

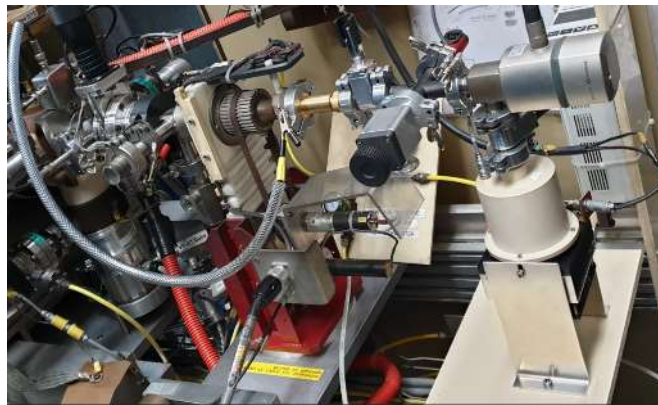
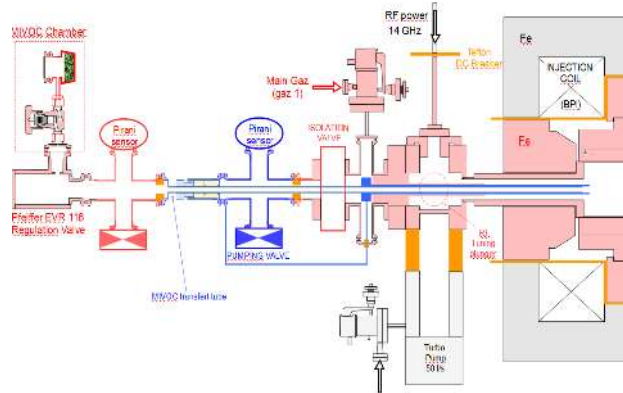


# Oven method



- A lot of isotopically enriched elements are evaporated by oven (oxyde and metallic form)
- Control of evaporation
- High charges states can be optimized

## MIVOC method



equipment to inject organometallic compound

## Metallic beams with MIVOC:

Ni, Fe, Mg, Cr, Ti

For natural elements : Several Commercial compounds can be found.

R&D to obtain synthesis with the isotopically enriched element.

=> B.GALL's team IPHC- Strasbourg

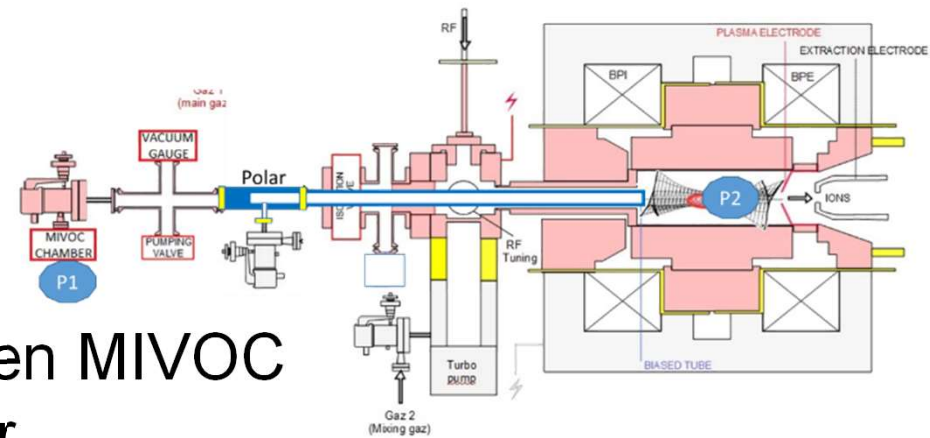
Several syntheses could be developed to replace the evaporation of element with high vapor pressure (difficulties of evaporation control with oven)

**In progress:** synthesis of Uranocene  
First test in March 2022 without success  
Second test in 2023

# Upgrade of MIVOC system (2021-2022)

Goal:

- ⇒ Optimization of regulation
- ⇒ Increase conductance between MIVOC chamber and plasma chamber
- ⇒ Design to stop the insulator metalization

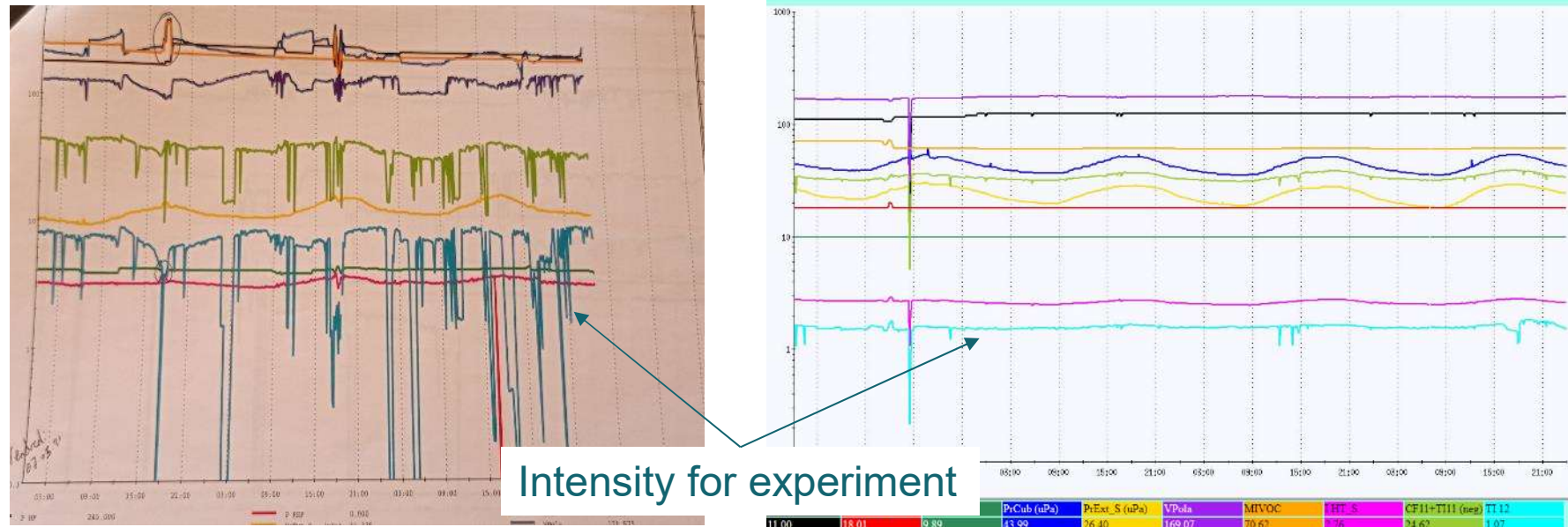


**RUN with  $^{58}\text{Ni}^{11+}$  :**  
20 e.  $\mu\text{A}$  for 31UT with better stability



# Upgrade of MIVOC system (2021-2022)

Results for 4 days before and after upgrade with  $^{58}\text{Ni}^{11+}$

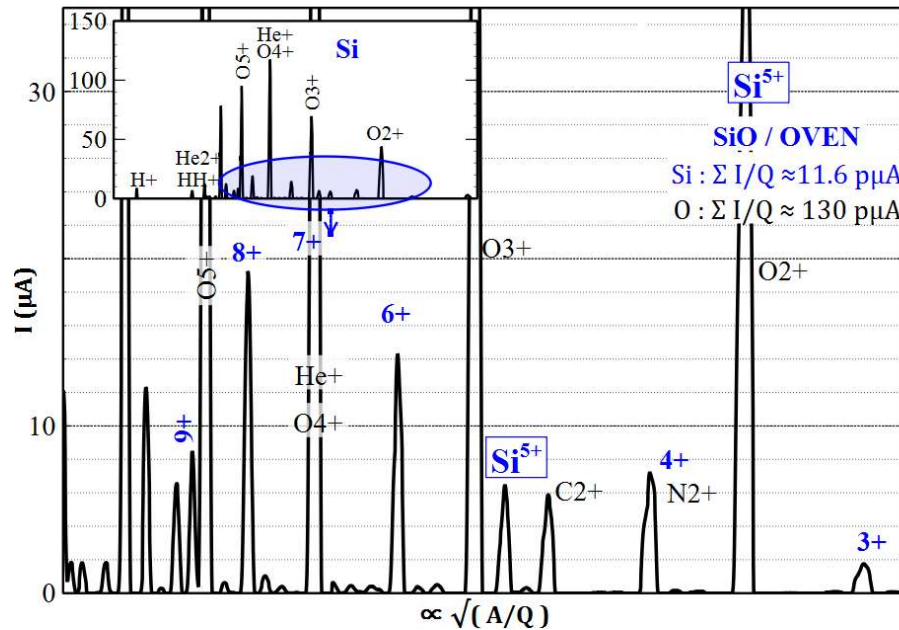
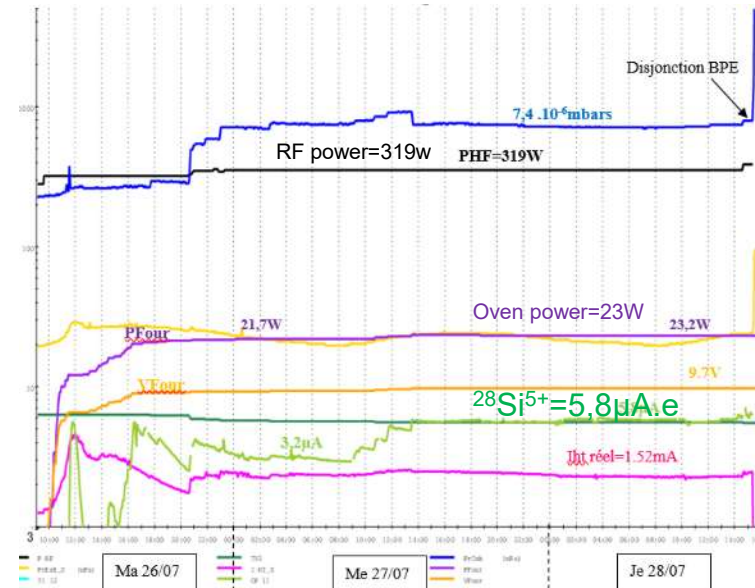


2021

2022

- ⇒ Intensity a little bit higher (20e.μA compare to 15e.μA)
- ⇒ More stable beam
- ⇒ Reduce tuning interventions along the experiment

# II- Silicon beam production



**Compound:** SiO natural  
**Vapor pressure :**  $10^{-2}$  mbars for  $1080^{\circ}$  C  
**Interest of using:** Several isotopically enriched samples with this compound ( $^{30}\text{SiO}$ ,  $^{29}\text{SiO}$ )

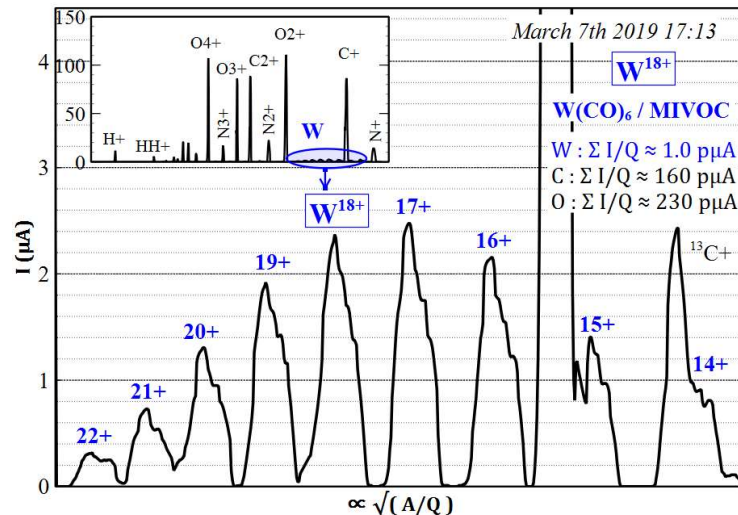
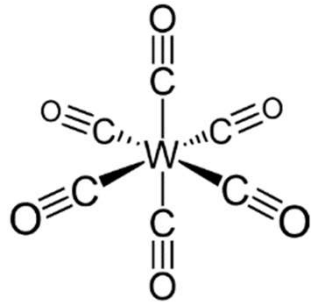
**Consumption:** 0,59mg/h of Si (0,89mg/h of SiO)  
**Efficiency:** 6%

**Example of beams available for physics**  
 $^{28}\text{Si}^{7/14+}$  at 95 MeV/A  $\rightarrow$  0,4 p.μA on the target  
 $^{30}\text{Si}^{7/14+}$  at 85 MeV/A  $\rightarrow$  0,4 p.μA on the target



# III-Tungsten beam production

**Compound:** tungsten hexacarbonyl  
 $W(CO)_6$

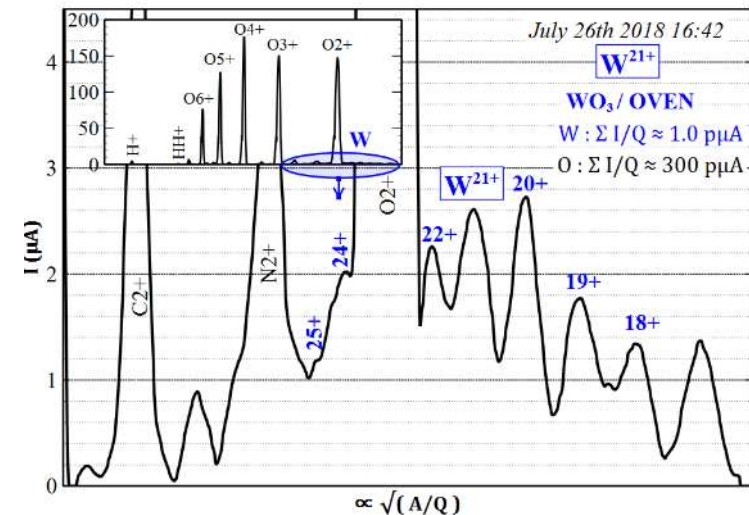
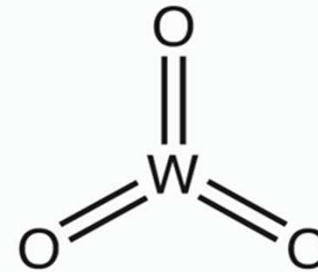


**Consumption:** 0,49mg/h of W (0,97mg/h of  $W(CO)_6$ )

**Efficiency:** 4,9%

$^{186}W^{20+} = 1.4e.\mu A$  (in the faraday cup after source)

**Compound:** tungsten trioxide-  $WO_3$  natural  
**Vapor pressure :**  $10^{-2}$  mbars for  $1176^\circ C$



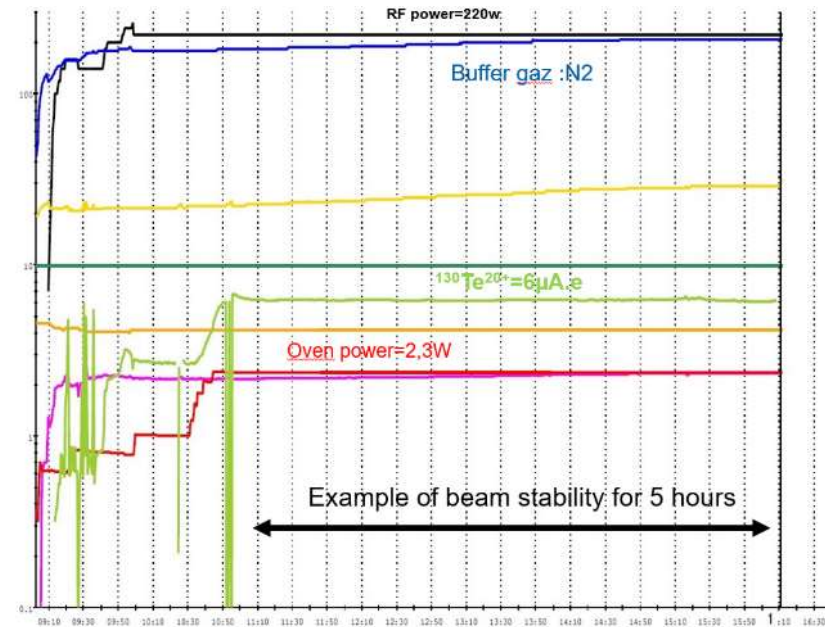
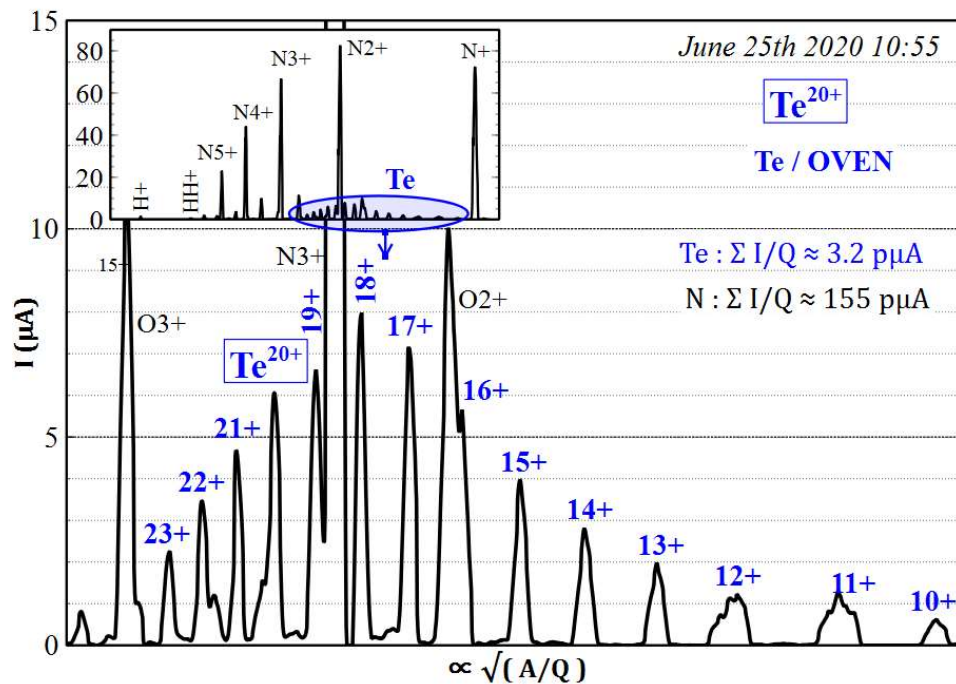
**Consumption:** 3,5 mg/h of W (4,5mg/h of  $WO_3$ )

**Efficiency:** 1,4%

$^{186}W^{20+} = 2.8e.\mu A$  (in the faraday cup after source)

$^{186}W^{24+}$  at 6 MeV/A  $\rightarrow$  11p.nA on the target

# IV-Tellurium beam production



**Compound:**  $^{130}\text{Te}$  (99,8% enriched sample)

**Vapor pressure :**  $10^{-2}$  mbar for  $360^\circ \text{C}$

**Melting point:**  $452^\circ \text{C}$

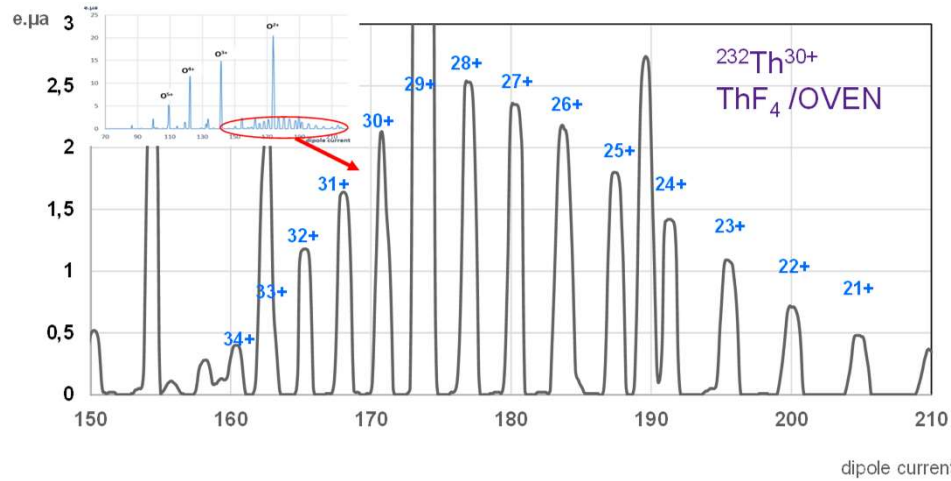
**Consumption:** 0,52mg/h of  $^{130}\text{Te}$

**Efficiency:** 7,5%

$^{130}\text{Te}^{20+}=6\text{e.}\mu\text{A}$  (on the faraday cup after ion source)

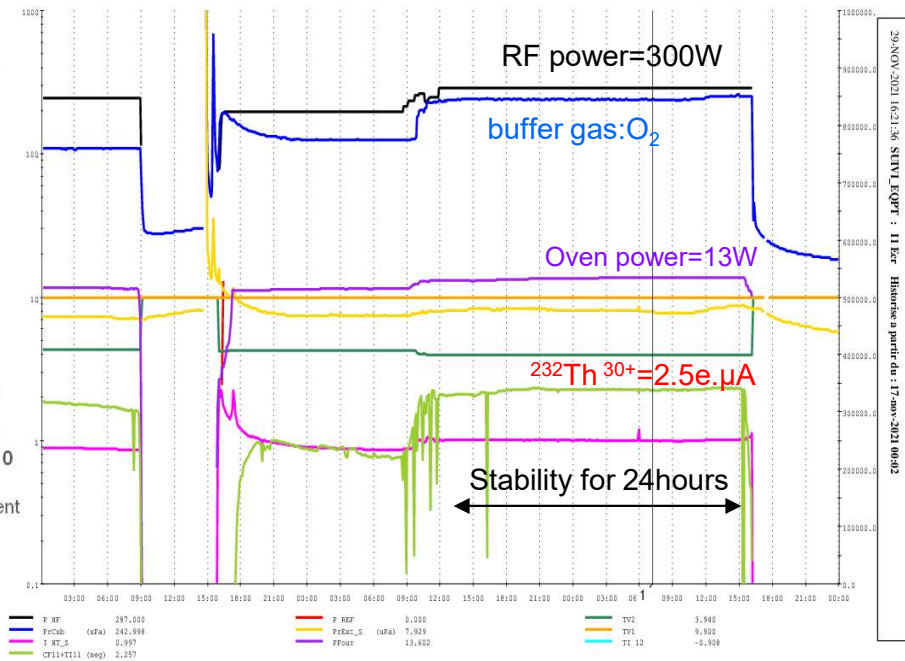
$^{130}\text{Te}^{19+}$  at 8 MeV/A  $\rightarrow$  50p.nA on the target

# V-Thorium beam production



**Compound:**  $^{232}\text{ThF}_4$   
**Vapor pressure :**  $10^{-2}$  mbar for  $950^\circ\text{C}$   
**Melting point:**  $1100^\circ\text{C}$

**Consumption:** 0,1mg/h of  $^{232}\text{Th}$   
**Efficiency:** 8%



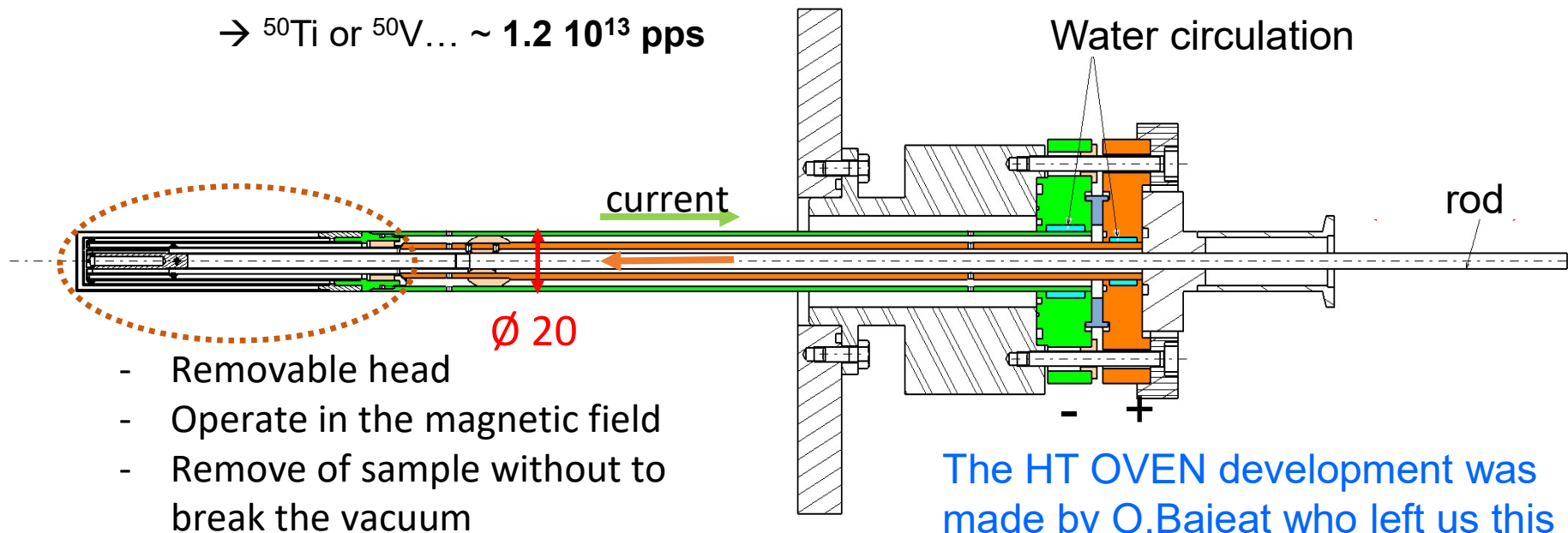
- VAMOS experiment proposal:  
 $^{232}\text{Th}^{30+}$  at 6,1MeV/A → 12p.nA on the target
- An other example of intensity  
 $^{232}\text{Th}^{34+}$  at 8MeV/A → 2p.nA on the target



## VI- The first beam tests with HT OVEN

### The goal of HT oven development

- ✓ For Ganil-Cyclotrons in ECR4 source:
  - increasing metallic beams intensities which are produced today by sputtering method ( $^{238}\text{U}$ ,  $^{181}\text{Ta}$ , ....)
- ✓ For Spiral 2 in **Phoenix V3\*** ECR IS:
  - $^{50}\text{Ti}$  or  $^{50}\text{V}$ ... ~  $1.2 \cdot 10^{13}$  pps

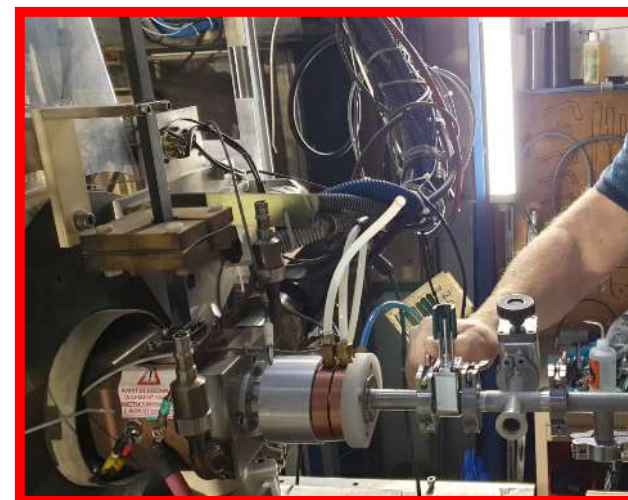
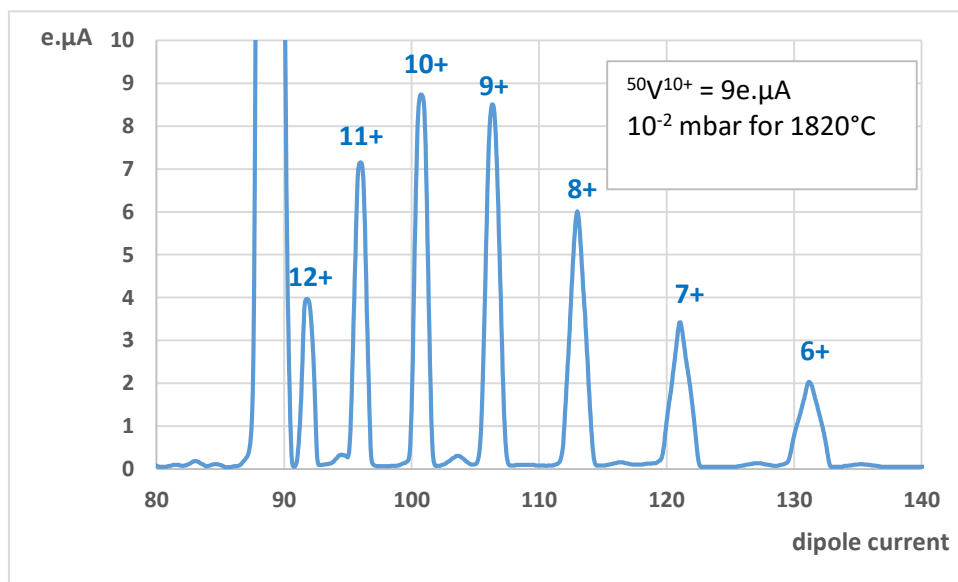
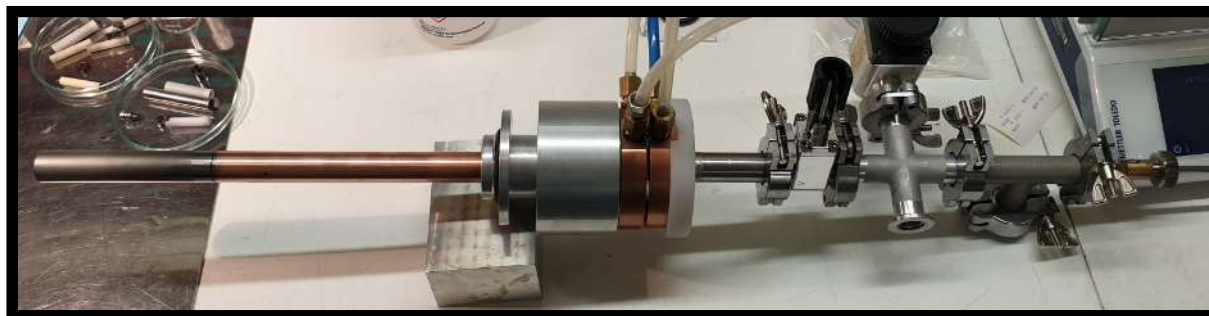


- Removable head
- Operate in the magnetic field
- Remove of sample without to break the vacuum

The HT OVEN development was made by O.Bajeat who left us this year.

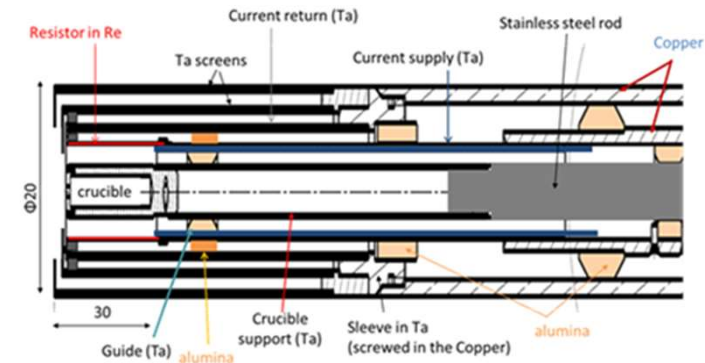
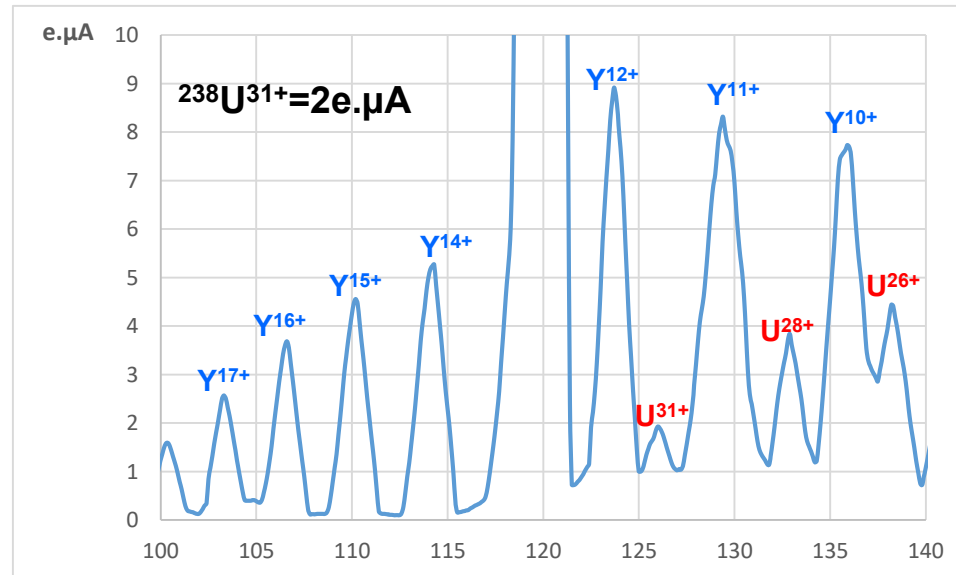
\*developed by LPSC (Grenoble)

# Test of vanadium in ECR4-M ion source



- 4 days of continue running with V and 25 days total operation in 2021
- Oven validated to evaporate Uranium

## Test of uranium in ECR4-M ion source



- Choice of crucible :  $\text{Y}_2\text{O}_3$  for compatibility with  $^{238}\text{U}$

- Yttrium pollution due to evaporation of crucible
- Intensity of Uranium interesting despite the pollution and the lower of ion source 's perform (modification of RF injection with HT oven)
- Next test with  $\text{UO}_2$



## V-Conclusion

- Four new ions beams availables (Si, W, Te, Th)
- Carbonyl compounds: New way to produce other metallic elements.
- News organometallic syntheses could be developped depending of physics request.
- HT oven up to 2000° C is a successful and useable for operation

Legend:

- Oven (Red)
- Gaz compound, MIVOC (Blue)
- Sputtering (Green)
- Plasma heating (Yellow)

H																	He
Li	Be											B	C	N	O	F	Ne
Na	Mg											Al	Si	P	S	Cl	Ar
K	Ca	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	Ga	Ge	As	Se	Br	Kr
Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	In	Sn	Sb	Te	I	Xe
Cs	Ba	*	Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Tl	Pb	Bi	Po	At	Rn
Fr	Ra	**															
*	La	Ce	Pr	Nd	Pm	Sm	Eu	Gd	Tb	Dy	Ho	Er	Tm	Yb	Lu		
**	Ac	Th	Pa	U													

Thank you for you attention!